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TRANSISTOR STRUCTURE
First Named Inventor: Joseph Smart
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Title of Invention	HIGH VOLTAGE GaN-BASED TRANSISTOR STRUCTURE	
<p>Application Number: 10/689979 </p> <p>Date: 2003-10-20</p> <p>First Named Applicant: Joseph Smart</p> <p>Confirmation Number: 3803</p> <p>Attorney Docket Number: 2867-207</p>		
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Benjamin S. Withrow Registered Number: 40,876	/benjamin s. withrow/	Attorney
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Comments		



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<h3>US Patent Documents</h3> <p>Note: Applicant is not required to submit a paper copy of cited US Patent Documents</p> <table border="1"><thead><tr><th>init</th><th>Cite.No.</th><th>Patent No.</th><th>Date</th><th>Patentee</th><th>Kind</th><th>Class</th><th>Subclass</th></tr></thead><tbody><tr><td></td><td>1</td><td>5608353</td><td>1997-03-04</td><td>Pratt</td><td></td><td>330</td><td>295</td></tr><tr><td></td><td>2</td><td>5629648</td><td>1997-05-13</td><td>Pratt</td><td></td><td>330</td><td>289</td></tr><tr><td></td><td>3</td><td>6130579</td><td>2000-10-10</td><td>Iyer et al.</td><td></td><td>330</td><td>285</td></tr><tr><td></td><td>4</td><td>6191656</td><td>2001-02-20</td><td>Nadler</td><td></td><td>330</td><td>288</td></tr><tr><td></td><td>5</td><td>6229395</td><td>2001-05-08</td><td>Kay</td><td></td><td>330</td><td>252</td></tr><tr><td></td><td>6</td><td>6265943</td><td>2001-07-24</td><td>Dening et al.</td><td></td><td>330</td><td>296</td></tr><tr><td></td><td>7</td><td>6271727</td><td>2001-08-07</td><td>Schmukler</td><td></td><td>330</td><td>284</td></tr><tr><td></td><td>8</td><td>6285239</td><td>2001-09-04</td><td>Iyer et al.</td><td></td><td>327</td><td>531</td></tr><tr><td></td><td>9</td><td>6307364</td><td>2001-10-23</td><td>Augustine</td><td></td><td>324</td><td>95</td></tr><tr><td></td><td>10</td><td>6313705</td><td>2001-11-06</td><td>Dening et al.</td><td></td><td>330</td><td>276</td></tr><tr><td></td><td>11</td><td>6329809</td><td>2001-12-11</td><td>Dening et al.</td><td></td><td>324</td><td>95</td></tr><tr><td></td><td>12</td><td>6333677</td><td>2001-12-25</td><td>Dening</td><td></td><td>330</td><td>296</td></tr><tr><td></td><td>13</td><td>6356150</td><td>2002-03-12</td><td>Spears et al.</td><td></td><td>330</td><td>145</td></tr></tbody></table>								init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass		1	5608353	1997-03-04	Pratt		330	295		2	5629648	1997-05-13	Pratt		330	289		3	6130579	2000-10-10	Iyer et al.		330	285		4	6191656	2001-02-20	Nadler		330	288		5	6229395	2001-05-08	Kay		330	252		6	6265943	2001-07-24	Dening et al.		330	296		7	6271727	2001-08-07	Schmukler		330	284		8	6285239	2001-09-04	Iyer et al.		327	531		9	6307364	2001-10-23	Augustine		324	95		10	6313705	2001-11-06	Dening et al.		330	276		11	6329809	2001-12-11	Dening et al.		324	95		12	6333677	2001-12-25	Dening		330	296		13	6356150	2002-03-12	Spears et al.		330	145
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	15	6369657	2002-04-09	Dening et al.	330	296
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	27	6750482	2004-06-15	Seaford et al.	257	191

Signature

Examiner Name	Date